NSN 5961-01-532-3573

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Inclosure Material:
Plastic or ceramic
Overall Length:
Between 1.070 inches and 1.182 inches
Terminal Length:
0.500 inches
Overall Height:
Between 0.160 inches and 0.190 inches
Overall Width:
Between 0.380 inches and 0.405 inches
Function For Which Designed:
Switching
End Application:
Nsn 4935-01-136-0233; shop equipment, guided missile system; w/s; missile, patriot
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-220ab
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 drain to source voltage
Current Rating Per Characteristic:
12.00 amperes source cutoff current of standard range
Power Rating Per Characteristic:
75.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Power mosfet, 12 amps, 100 volts; p-channel to -220
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0